

HT201XX One Lamp/LED Flash Driver

Features

- CMOS Metal-Gate Process Technology
- Operating voltage: 1.2V~4.5V
- Low standby current: 1µA Typ. at 3V
- Built-in oscillator (F_{OSC}: 32KHz)
- ON/OFF control function for the HT2013H, HT2013M, HT2013L
- 1/8 duty cycle output
- Directly driving an LED
- Minimum external components
- TO-92 package (only for the HT2012H, HT2014M, HT2014L)

- Flash rate options:
 - HT2013H \rightarrow about 4Hz
 - $HT2012H \rightarrow about 4Hz$
 - (No ON/OFF control function)
 - $HT2013M \rightarrow about 2Hz$
 - $HT2014M \rightarrow about 2Hz$
 - (No ON/OFF control function)
 - $HT2013L \rightarrow about 1Hz$
 - $HT2014L \rightarrow about 1Hz$

(No ON/OFF control function)

General Description

The HT201XX series is a low cost, low power CMOS LSI chip designed for lamp and LED flash drivers. It can be operated without any external components, thus suitable for applica-

tions on flashing badges, gift cards, flashing earrings, and other products that require flashing lights.

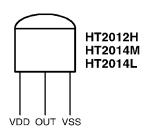
Selection Table

Part No.	Flash Rate	ON/OFF Control		Package		
		Yes	No	TO-92	Dice	
HT2013H	4Hz	√			√	
HT2012H	4Hz		√	√	√	
HT2013M	2Hz	√			√	
HT2014M	2Hz		√	√	√	
HT2013L	1Hz	√			√	
HT2014L	1Hz		√	√	√	

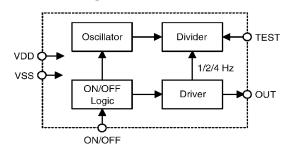
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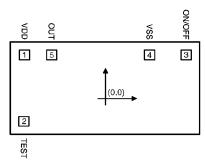
Pin Assignment



Block Diagram



Pad Coordinates



Unit: mil

Pad No.	X	Y		
1	-23.9	13.5		
2	-24.13	-7.055		
3	23.89	13.5		
4	13.09	13.5		
5	-15.89	13.5		

Chip size: $60 \times 38 \text{ (mil)}^2$

Pad Description

Pad No.	Pad Name	I/O	Internal Connection	Description
1	VDD	_	_	Power supply (positive)
2	TEST	_	_	For IC test only
3	ON/OFF	I	CMOS Pull-High	Lamp/LED flash ON/OFF control pad
4	VSS		_	Power supply (ground)
5	OUT	0	NMOS Open Drain	Lamp/LED flash output

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^{*}The IC substrate should be connected to VDD in PCB layout artwork.



Absolute Maximum Ratings

Supply Voltage0.3V to 5.5V	Storage Temperature $-50 ^{\circ}\mathrm{C}$ to $125 ^{\circ}\mathrm{C}$
Input VoltageVss-0.3V to Vpp+0.3V	Operating Temperature20°C to 75°C

Electrical Characteristics

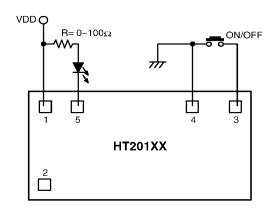
(Ta=25°C)

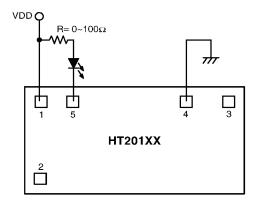
Symbol	Parameter	Test Condition		Min.	Т	Max.	Units
	Parameter	V _{DD}	Condition	141111.	Тур.	Max.	Onits
$ m V_{DD}$	Operating Voltage	_	_	1.2	3	4.5	v
I_{STB}	Standby Current	3V	_	_	1	2	μА
$I_{ m DD}$	Operating Current	3V	No load	_	200	500	μА
$I_{ m OL}$	OUT Pad Sink Current	1.5V	$V_{\rm OL}$ =0.15 V	5	12	_	mA
		3V	V _{OL} =0.3V	10	30	_	mA
Fosc	System Frequency	3V	_	_	32K	_	Hz

Application Circuit

Chip form with ON/OFF control

Chip form without ON/OFF control



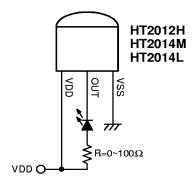


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Package form application



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